To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

DATA SHEET

MOS FIELD EFFECT TRANSISTOR
NP109N04PUG

SWITCHING
N-CHANNEL POWER MOS FET

DESCRIPTION

The NP109N04PUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

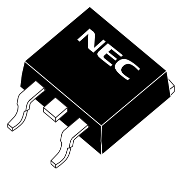
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP109N04PUG-E1-AY Note	Pure Sn (Tin)	Tape 800 p/reel	TO-263 (MP-25ZP) typ. 1.5 g
NP109N04PUG-E2-AY Note			

Note Pb-free (This product does not contain Pb in external electrode).

FEATURES

- Super low on-state resistance
  $R_{DS(on)}$ = 2.3 mΩ MAX. (V_{GS} = 10 V, I_D = 55 A)
- High current rating $I_{D(DC)}$ = ±110 A

(TO-263)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	40	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±20	V
Drain Current (DC) (T_C = 25°C)	$I_{D(DC)}$	±110	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	±440	A
Total Power Dissipation (T_C = 25°C)	P_{T1}	220	W
Total Power Dissipation (T_A = 25°C)	P_{T2}	1.8	W
Channel Temperature	T_{ch}	175	°C
Storage Temperature	T_{stg}	–55 to +175	°C
Repetitive Avalanche Current Note2	I_{AR}	60	A
Repetitive Avalanche Energy Note2	E_{AR}	360	mJ

Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. T_{ch} ≤ 150°C, V_{DD} = 20 V, R_G = 25 Ω, V_{GS} = 20 → 0 V

THERMAL RESISTANCE

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	0.68	°C/W
Channel to Ambient Thermal Resistance	$R_{th(ch-A)}$	83.3	°C/W

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Date Published December 2007 NS
Printed in Japan

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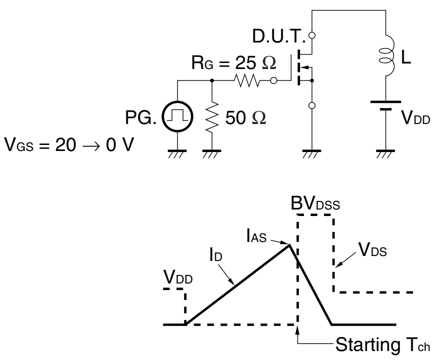
The mark <R> shows major revised points.
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

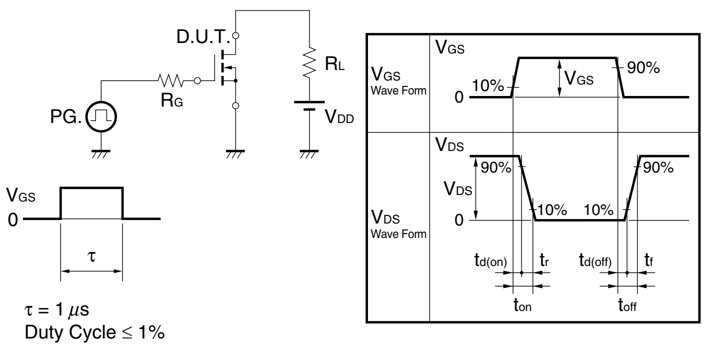
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 40 V, V_{GS} = 0 V			1	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance	$\| y_{fs} \|$	V_{DS} = 10 V, I_D = 55 A	31	63		S
Drain to Source On-state Resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 55 A		1.7	2.3	mΩ
<R> Input Capacitance	C_{iss}	V_{DS} = 25 V,		10500	15750	pF
<R> Output Capacitance	C_{oss}	V_{GS} = 0 V,		980	1470	pF
<R> Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		630	1140	pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 20 V, I_D = 55 A,		47	103	ns
Rise Time	t_r	V_{GS} = 10 V,		35	70	ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 0 Ω		90	180	ns
Fall Time	t_f			35	70	ns
Total Gate Charge	Q_G	V_{DD} = 32 V,		180	270	nC
Gate to Source Charge	Q_{GS}	V_{GS} = 10 V,		44		nC
Gate to Drain Charge	Q_{GD}	I_D = 110 A		64		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 110 A, V_{GS} = 0 V		0.9	1.4	V
Reverse Recovery Time	t_{rr}	I_F = 110 A, V_{GS} = 0 V,		56		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		80		nC

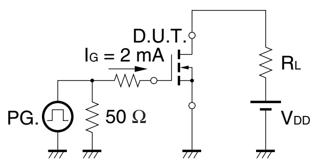
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

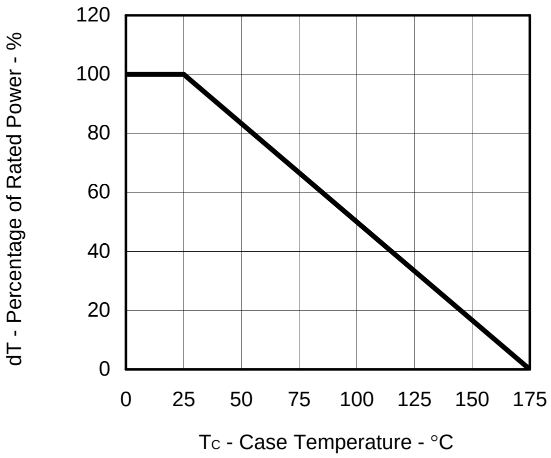


TEST CIRCUIT 3 GATE CHARGE

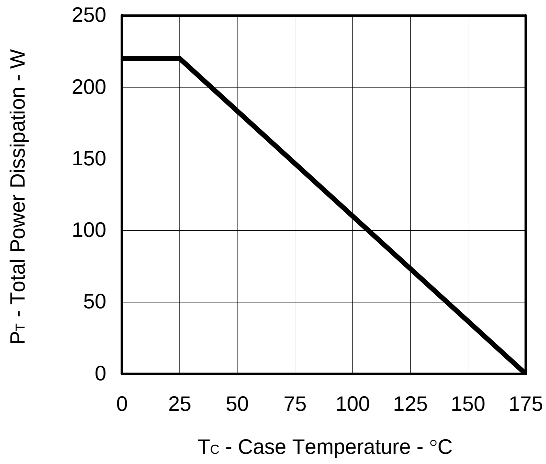


TYPICAL CHARACTERISTICS (T_A = 25°C)

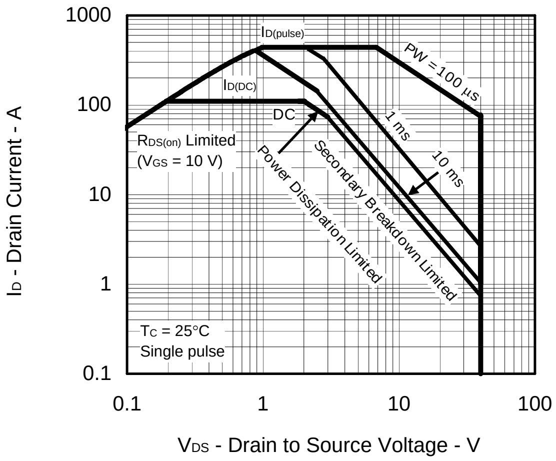
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



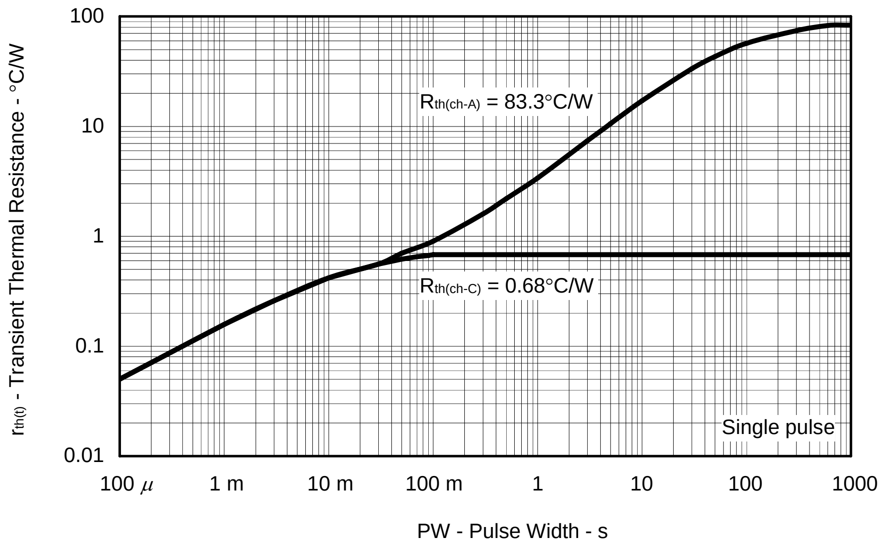
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



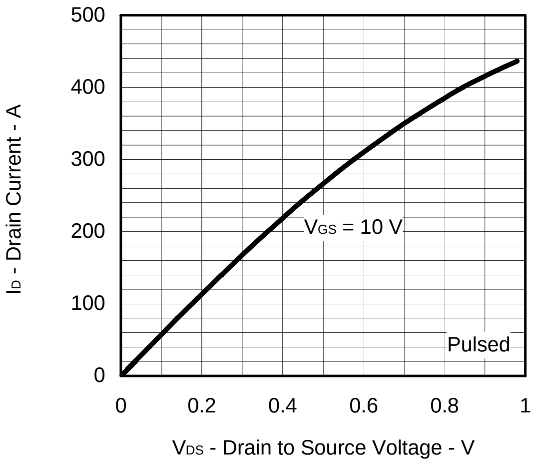
FORWARD BIAS SAFE OPERATING AREA



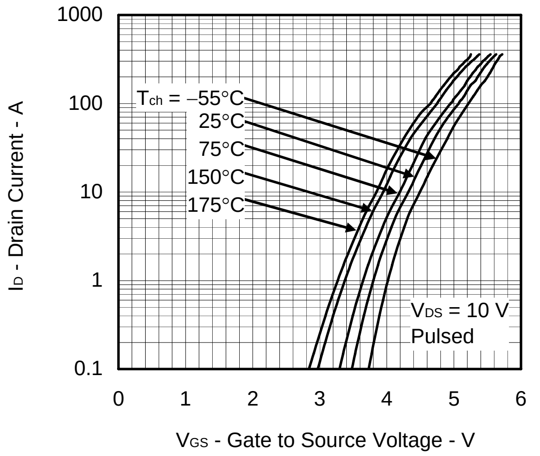
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



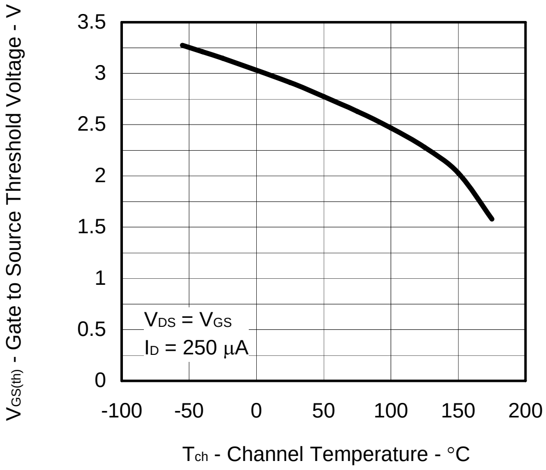
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



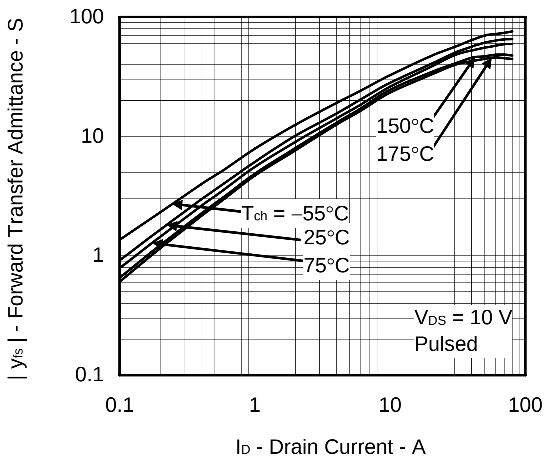
FORWARD TRANSFER CHARACTERISTICS



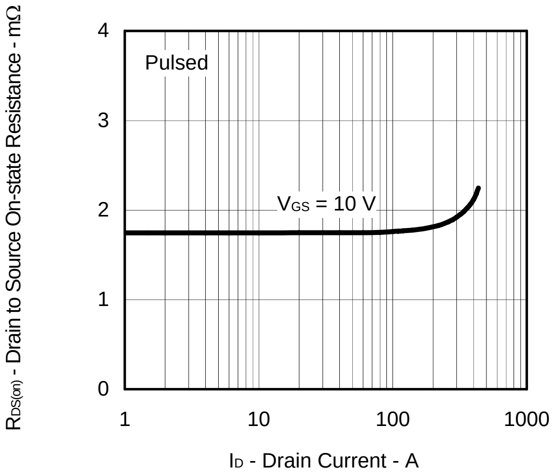
GATE TO SOURCE THRESHOLD VOLTAGE vs.
CHANNEL TEMPERATURE



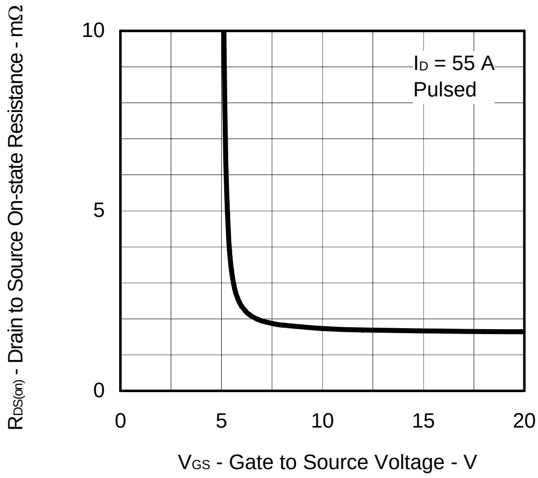
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



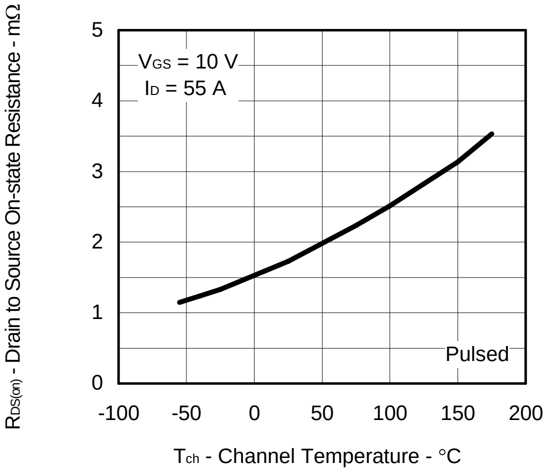
DRAIN TO SOURCE ON-STATE RESISTANCE
vs.
DRAIN CURRENT



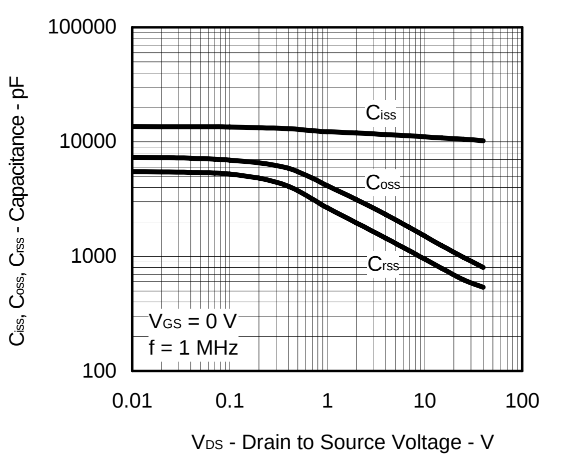
DRAIN TO SOURCE ON-STATE RESISTANCE
vs.
GATE TO SOURCE VOLTAGE



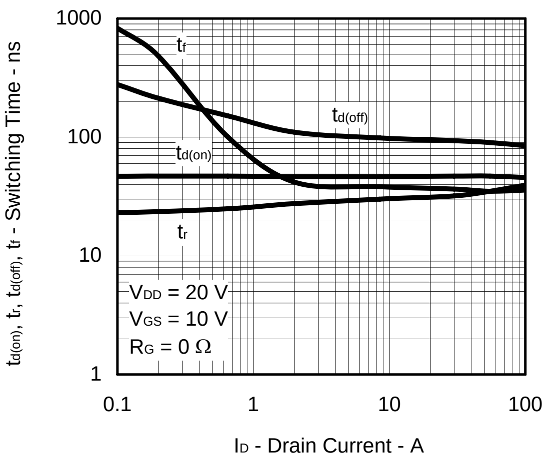
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



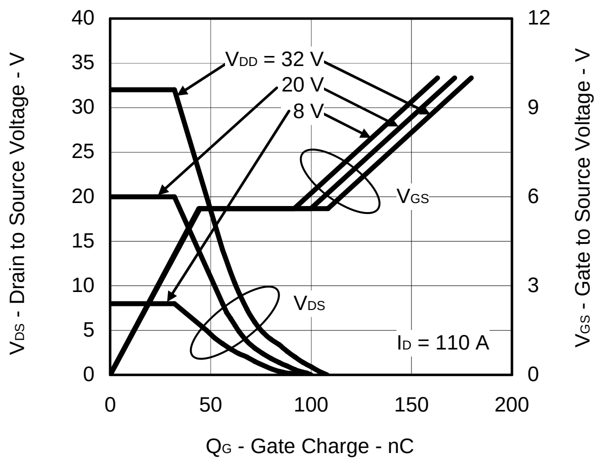
<R> CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



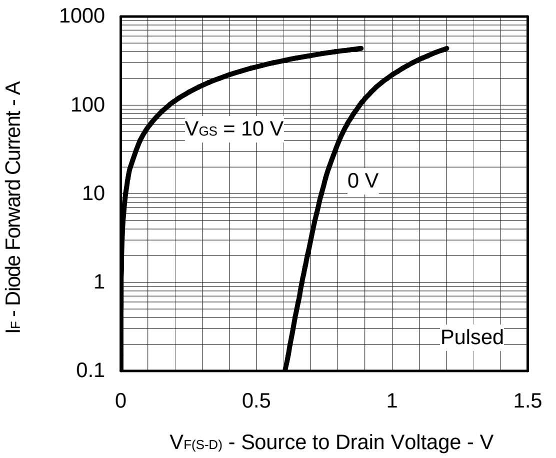
SWITCHING CHARACTERISTICS



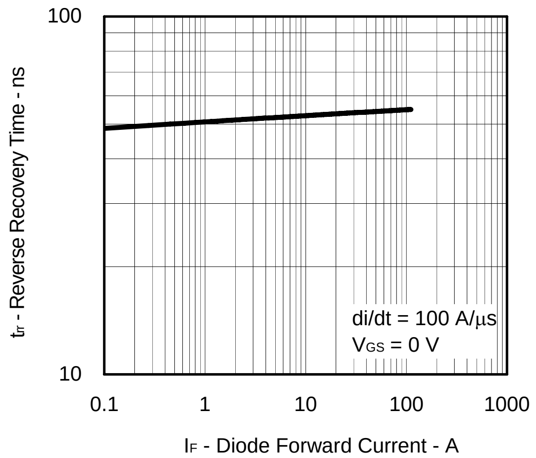
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

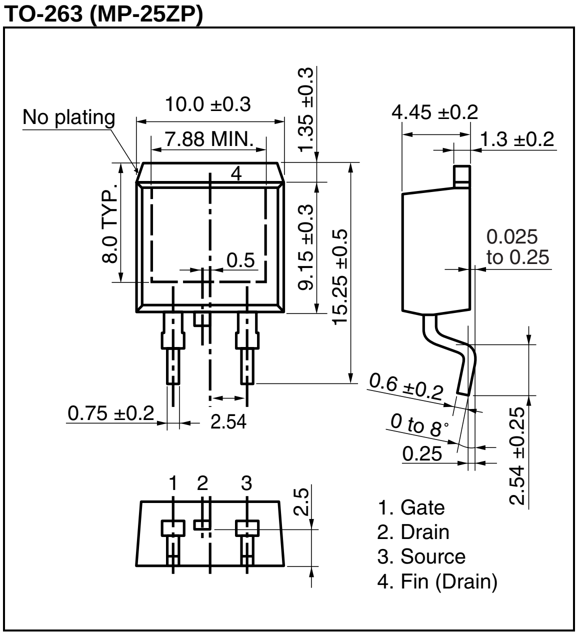


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

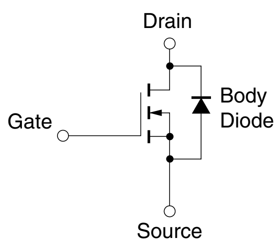


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZP)



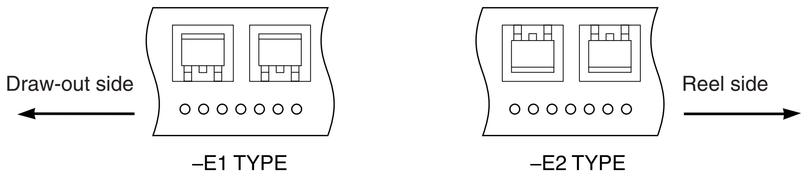
EQUIVALENT CIRCUIT



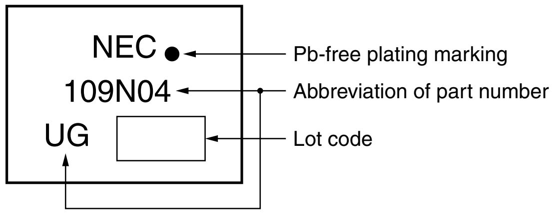
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP109N04PUG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	IR60-00-3
Partial heating	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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